

List of participants
International Conference on the Science and Application of Nanotubes - NT16

Last name	First name	Affiliation	Country
Abdulimu	Abasi	IMDEA NANOCIENCIA	Spain
Adhikari	Subash	IBS, Center for Integrated Nanostructure Physics, Sungkyunkwan University	South Korea
AeRi	Lee	TAEYANG3C	South Korea
Agustina	Elsye	Sejong University	South Korea
Ahlskog	Markus	University of Jyväskylä	Finland
Ahmad Pour Monazam	Mohammad Reza	Physik Nanostrukturierter Materialien	Austria
Akahane	Kouichi	National Institute of Information and Communications Technology	Japan
Akca	Sevilay	School of Physics and CRANN, Trinity College Dublin	Ireland
Akiba	Sachie	Waseda University	Japan
Akita	Seiji	Osaka Prefecture University	Japan
Alvarez	Laurent	Laboratoire Charles Coulomb	France
An	Hua	Department of Mechanical Engineering, The University of Tokyo	Japan
Ando	Yasunobu	Department of Materials Engineering, The University of Tokyo	Japan
Anisimov	Anton	Canatu Ltd.	Finland
Arenal	Raul	Universidad de Zaragoza	Spain
Argentero	Giacomo	Physik Nanostrukturierter Materialien	Austria
Arpacay	Pinar	School of Physics and CRANN, Trinity College Dublin	Ireland
Asano	Satoshi	TASC	Japan
Atlibatur	Rüya	Istanbul Technical University	Turkey
Ayria	Pourya	Tohoku University	Japan
Bai	Jinbo	CNRS ECParis	France
Bayer	Bernhard	Physik Nanostrukturierter Materialien	Austria
Berkmann	Claudia	University of Vienna	Austria
Bernholc	Jerry	NC State University	USA
Bezrodnny	Alexandr	OCSAI Group	Russian Federation
Bichara	Christophe	CINAM, CNRS and Aix-Marseille University	France
Bichot	Philippe	OCSAI Group	Austria
Blaha	Peter	Materialchemie, TU Vienna	Austria
Blaudeck	Thomas	TU Chemnitz	Germany
Bockrath	Marc	UC Riverside	USA
Boghossian	Ardemis	Ecole Polytechnique Federale de Lausanne (EPFL)	Switzerland
Bondarev	Igor	North Carolina Central University	USA
Borin Barin	Gabriela	EMPA	Switzerland
Böttger	Simon	ZfM / TU Chemnitz	Germany
Bouanis	Fatima	Ecole Polytechnique	France
Bushmaker	Adam	The Aerospace Corporation	USA
Caldevilla	Andres	DENSO AUTOMOTIVE Deutschland GmbH	Germany
Cambré	Sofie	University of Antwerp	Belgium
Caneva	Sabina	University of Cambridge	United Kingdom
Cao	Kecheng	Electron Microscopy of Materials Science, Central Facility for Electron Microscopy, Ulm University	Germany
Castan	Alice	Institut de chimie moléculaire et des matériaux d'Orsay (ICMMO)	France
Charon	Emeline	CEA Saclay, Université Paris Saclay	France
Chen	Bingyan	Key Laboratory for the Physics and Chemistry of Nanodevices, Department of Electronics, Peking University	China
Chen	Chiing-Chang	National Taichung University of Education	Taiwan
Chen	Mo	Tsinghua University	China
Chen	Tianchi	Department of Chemical engineering, Tsinghua University	China

Chen	Yuan	The University of Sydney	Australia
Cheng	Guo-an	Beijing Normal University	China
Cheng	Hui-Ming	Institute of Metal Research, CAS	China
Chenxing	Wang	Nagoya University	Japan
Chiashi	Shohei	The University of Tokyo	Japan
Chimborazo	Johnny	University of Vienna	Ecuador
Cho	Jae Whan	Konkuk University	South Korea
Choi	Sung-Yool	KAIST	South Korea
Chu	Haibin	Inner Mongolia University	China
Chung	Hyun-Jong	Konkuk University	South Korea
Chuvilin	Andrey	CIC nanoGUNE Consolider	Spain
Datao	Wang	Tsinghua University	China
Davodi	Fatemeh	Aalto university, school of chemical technology, Department of chemistry	Finland
Dervishi	Enkeleda	Los Alamos National Laboratory	USA
Dinse	Klaus-Peter	FU Berlin	Germany
Domanov	Oleg	Elektronische Materialeigenschaften	Austria
dos Santos	Maria Cristina	Universidade de São Paulo	Brazil
Dozortsev	Alexander	Technion - Israel Institute of Technology	Israel
Dubov	Dmitry	ISCTE LLC	Russian Federation
Duong	Hai	National University of Singapore	Singapore
Ekspong	Joakim	Department of Physics	Sweden
Elibol	Kenan	Physik Nanostrukturierter Materialien	Austria
Fedi	Filippo	Elektronische Materialeigenschaften	Austria
Fedorov	Georgy	Moscow Institute for physics and Technology	Russian Federation
Fernandes	Ricardo	Division of Applied Physical Chemistry, KTH Royal Institute of Technology	Sweden
Ferrer-Anglada	Nuria	Universitat Politècnica de Catalunya	Spain
Fink	Joerg	IFW Dresden	Germany
Flahaut	E	CNRS	France
Flavel	Benjamin	Karlsruhe Institute of Nanotechnology	Germany
Forel	Salome	ecole polytechnique	France
Fuchs	Florian	Helmholtz-Zentrum Dresden Rossendorf	Germany
Fujigaya	Tsuyohiko	Kyushu University	Japan
Fujigaya	Tsuyohiko	Kyushu University	Japan
Fukuhara	Satoru	The University of Tokyo	Japan
Gao	Yanlin	Graduate School of Pure and Applied Sciences, University of Tsukuba	Japan
Garcia Zuñiga	Miguel Angel	Technological Institute of Celaya	Mexico
Garlof	Svenja	Technische Universität Hamburg-Harburg	Germany
Gaufrès	Etienne	CNRS-Onera	France
GHAG	VIK	G.M.S TECHNOLOGIES CO.,LTD	Thailand
Gillen	Roland	TU Berlin	Germany
Goldoni	Andrea	Elettra	Italy
Goldshtein	Israel	Technion - Israel Institute of Technology	Israel
Golser	Robin	Isotopenforschung und Kernphysik	Austria
Graf	Arko	Heidelberg University	Germany
Green	Micah	Texas A&M University	USA
Grimm	Stefan	Universität Heidelberg, Institute for Physical Chemistry	Germany
Guerrero	Jose	Graphenstone	Germany
Gulyutin	Nick	OCSiAI Group	Russian Federation
Hachiya	Soichiro	Department of applied chemistry, Waseda Univ.	Japan
Hafizi	Roohollah	Skolkovo Institute of Science and Technology	Russian Federation
Hakonen	Pertti	Aalto University	Finland
Haluska	Miro	Micro and Nanosystems, ETH Zurich	Switzerland
Hartmann	Martin	ZfM / TU Chemnitz, cfaed Dresden	Germany
Hasdeo	Eddwi	Tohoku University	Japan
Hata	Kenji	AIST	Japan
Hatakeyama	Rikizo	Tohoku University, Department of Electronic Engineering	Japan
Heeg	Sebastian	Photonics Laboratory, ETH Zürich	Switzerland

Heinz	Tony	Stanford University	USA
Hennrich	Frank	Karlsruhe Institute of Technology (KIT), Institute of Nanotechnology	Germany
Hermann	Sascha	TUC / Center for Advancing Electronics Dresden	Germany
Hernández-Martínez	Asiel	Universidad de Artemisa	Cuba
Hertel	Tobias	Julius-Maximilians-University	Germany
Hirata	Eri	Department of Oral Functional Prosthodontics, Graduate School of Dental Medicine, Hokkaido University	Japan
Hirotani	Jun	Nagoya University	Japan
Hirsch	Andreas	Department of Chemistry and Pharmacy & Interdisciplinary Center for Molecular Materials (ICMM)	Germany
Holtzl	Tibor	Furukawa Electric institute of Technology	Hungary
Homma	Yoshikazu	Tokyo University of Science	Japan
Hong	Jindui	University of Oxford	United Kingdom
Hou	Bo	National Institute of Advanced Industrial Science and Technology	Japan
Hu	Dongmei	Suzhou Institute of Nanotech and Nanobionics, CAS	China
Hummel	Stefan	Physik Nanostrukturierter Materialien	Austria
Hussain	Aqeel	NanoMaterials Group, Aalto University	Finland
Hüttel	Andreas K.	University of Regensburg	Germany
Hyun	Yesub	Sejong University	South Korea
Iakovlev	Vsevolod	skolkovo institute of science and technology	Russian Federation
Ileana	Florea	LPICM, CNRS, Ecole Polytechnique, Universite Paris-Saclay	France
Iliut	Maria	University of Manchester	United Kingdom
Ilyanovich	Oxana	OCSiAI Group	Russian Federation
Imadate	Konan	Osaka University	Japan
Inoue	Taiki	The University of Tokyo	Japan
Iseki	Keizo	SHOWA DENKO K.K.	Japan
Ishida	Takashi	Osaka University	Japan
Isoniemi	Tommi	University of Jyväskylä	Finland
Izard	Nicolas	Univ. Montpellier	France
Izumida	Wataru	Tohoku University	Japan
Janas	Dawid	University of Cambridge	United Kingdom
Jeon	Sang Koo	Korea Research Institute of Standards and Science	South Korea
JEONG	HYEONSU	KOREA INSTITUTE OF SCIENCE AND TECHNOLOGY	South Korea
Jhih-Siang	Yang	National Taiwan University of Science and Technology	Taiwan
Jiang	Hua	Department of Applied Physics, Aalto University School of Science	Finland
Jin	Chuanhong	Zhejiang University	China
Jordan	Kevin	BNNT	Austria
Jorio	Ado	UFMG	Brazil
Kallio	Tanja	Aalto University	Finland
Kamarás	Katalin	Wigner Research Centre for Physics	Hungary
Kanahashi	Kaito	Department of Advanced Science and Engineering, Waseda University	Japan
Kanda	Akinobu	University of Tsukuba	Japan
Kang	Cheon-Soo	Faculty of Engineering, Shinshu University	Japan
Kang	Lixing	Suzhou Institute of Nanotech and Nanobionics, CAS	China
Kang	Seoung-Hun	Kyung Hee University	South Korea
Katagiri	Susuma	Mitsubishi Corporation	Japan
Kataura	Hiromichi	NMRI, AIST	Japan
Kato	Takashi	Tokyo University of Science	Japan
Kato	Tomonori	Nagoya University	Japan
Kato	Toshiaki	Tohoku University	Japan
Kauppinen	Esko	Aalto University	Finland
Khalilov	Umedjon	University of Antwerp	Belgium
Kharlamova	Marianna	Faculty of Physics, University of Vienna	Austria

Kim	Duckjong	Korea Institute of Machinery and Materials	South Korea
KIM	JIMIN	SK innovation	Austria
Kim	Un Jeong	Samsung Advanced Institute of Technology	South Korea
Kling	Jens	Technical University of Denmark, DTU Cen (Center for Electron Nanoscopy)	Denmark
Kobashi	Kazufumi	National institute of advanced industrial science and technology	Japan
Kobayashi	Daiki	Osaka Prefecture University	Japan
Kobayashi	Yoshihiro	Osaka University	Japan
Kobayashi	Yoshihiro	Osaka University	Japan
Köhne	Martin	Robert Bosch GmbH	Germany
Kolanowska	Anna	Silesian University of Technology	Poland
Kollarics	Sándor	Budapest University of Technology and Economics	Hungary
Konczak	Lukasz	Jerzy Haber Institute of Catalysis and Surface Chemistry Polish Academy of Sciences	Poland
Kong	Jing	MIT	USA
Kono	Junichiro	Rice University	USA
Koshino	Mikito	Tohoku University	Japan
Kramberger-Kaplan	Christian-Rüdiger	Physik Nanostrukturierter Materialien	Austria
Krasnikov	Dmitry	Novosibirsk State University/Boreskov Institute of Catalysis	Russian Federation
Kresse	Georg	University of Vienna	Austria
Krupke	Ralph	Karlsruhe Institute of Technology	Germany
Kukucska	Gergo	Eotvos Lorand University	Hungary
Kuwahara	Yuki	AIST	Japan
Kuzmany	Hans	Universität Wien, Fakultät für Physik	Austria
Lagier	Laura	EcoLab, CNRS, INPT, UPS, Toulouse	France
Laiho	Patrik	Aalto University, Department of Applied Physics	Finland
Laiho	Patrik	Aalto University, Department of Applied Physics	Finland
Lee	Byeong-Kyu	University of Ulsan	South Korea
Lefebvre	Jacques	National Research Council	Canada
Levshov	Dmitry	Southern Federal University	Russian Federation
Li	Dongqi	Tsinghua University	China
Li	Qingwen	Suzhou Institute of Nanotech and Nanobionics, CAS	China
Li	Wenshan	Karlsruhe Institute of Technology	Germany
Li	Yan	Peking University	China
Liang	Shuai	McMaster University	Canada
Liang	Xuelei	Peking University	China
Lin	Jarnn-Horng	National University of Tainan	Taiwan
Liu	Chang	Institute of Metal Research, CAS	China
Liu	Huaping	Institute of Physics, Chinese Academy of Sciences	China
Liu	Kai	Associate Professor, Tsinghua University	China
Liu	Kaihui	Peking University	China
Liu	Peng	Tsinghua University	China
Liu	Yang	Academy for Advanced Interdisciplinary Studies, Peking University	China
Liu	Zheng	National Institute of Advanced Industrial Science and Technology (AIST)	Japan
Liu	Zhuang	Institute of Functional Nano & Soft Materials (FUNSOM)	China
Loiseau	Annick	LEM,	France
Longo	Carrie A.	BNNT, LLC	USA
Lopez	Alexander	Yachay Tech	Ecuador
Ludacka	Ursula	Physik Nanostrukturierter Materialien	Austria
Luo	Yufeng	Tsinghua University	China
Lurz	Christian	Universität Osnabrück	Germany
Ma	Yuxiao	Beihang University	China
Maki	Hideyuki	Keio University, JST PRESTO	Japan
Malik	Sharali	Karlsruhe Institute of Technology	Germany
Maliniak	Sharon	Technion	Israel
Marganska	Magdalena	University of Regensburg	Germany
Márkus	Bence Gábor	Budapest University of Technology and Economics	Hungary

Martinez	Dean	National Taiwan University of Science and Technology	Taiwan
Martinez	Dean	National Taiwan University of Science and Technology	Taiwan
Maruyama	Mina	University of Tsukuba	Japan
Maruyama	Shigeo	The University of Tokyo	Japan
Marx	Janik	Technical University Hamburg-Harburg	Germany
Matsuki	Keiichiro	Waseda University	Japan
Matsumoto	Naoyuki	1) Technology Research Association for Single Wall Carbon Nanotubes 2) The National Institute of Advanced Industrial Science and Technology	Japan
Mcsweeney	Robert	University of Nottingham	United Kingdom
Meyer	Carola	Universität Osnabrück	Germany
Mittelberger	Andreas	Physik Nanostrukturierter Materialien	Austria
Miyamoto	Yoshiyuki	AIST	Japan
Miyoshi	Yusuke	Keio University	Japan
Moon	Sookyoung	Japan Aerospace Exploration Agency	Japan
Morais	Manuel	Fraunhofer Institute for Chemical Technology (ICT)	Germany
Mossegård	Jonatan	Umeå University	Sweden
Motaragheb Jafarpour	Saeed	Center for Microtechnologies, TU Chemnitz	Germany
Mukai	Ken	Inorganic Functional Materials Research Institute, National Institute of Advanced Industrial Science and Technology (AIST)	Japan
Mustonen	Kimmo	Physik Nanostrukturierter Materialien	Austria
Myo Myint	Sandar	National University of Singapore	Singapore
Nakanishi	Takeshi	AIST	Japan
Nakano	Motohiro	Nara Institute of Science and Technology	Japan
Nasibulin	Albert	Skolkovo Institute of Science and Technology	Russian Federation
Negishi	Ryota	Osaka University	Japan
Nguyen	Hung	Hanoi Institute of Chemistry and Materials Science	Vietnam
Nguyen	Van Luan	SKKU	South Korea
Niklas	Michael	Institut für Theoretische Physik	Germany
Nir	Hadar	Technion & Israel Institute of Technology	Israel
Noda	Suguru	Waseda University	Japan
Novotny	Lukas	ETH Zürich	Switzerland
Nugraha	Ahmad	Department of Physics, Tohoku University	Japan
Numata	Hideaki	Technology Research Association for Single Wall Carbon Nanotubes (TASC)	Japan
Ohfuchi	Mari	Fujitsu Laboratories	Japan
Ohkubo	Michio	Furukawa Electric Co., Ltd.	Japan
Ohno	Yutaka	Nagoya University	Japan
Okada	Susumu	University of Tsukuba	Japan
Okada	Takeru	Tohoku University	Japan
Okazaki	Toshiya	AIST	Japan
Okigawa	Yuki	National Institute of Advanced Industrial Science and Technology	Japan
Ono	Youky	Research organization for information science & technology	Japan
Ordokhani	Fereshteh	Istanbul Technical University	Turkey
Otsuka	Keigo	The University of Tokyo	Japan
Palotás	Julianne	Budapest University of Technology and Economics	Hungary
Panczyk	Tomasz	Institute of Catalysis and Surface Chemistry	Poland
Panes Ruiz	Luis Antonio	Chair of Materials Science and Nanotechnology, TU Dresden	Germany
Park	Ji Hyun	Physics and Materials Science Research Unit, Université du Luxembourg	Luxemburg
Park	Ji-Yong	Ajou University	South Korea
Pekker	Sandor	Wigner RCP ISSPO	Hungary
Peng	Lian-Mao	Peking University	China
Peng	Rui	Institute of Functional Nano & Soft Materials (FUNSOM), Soochow University	China
Perebeinos	Vasili	Skoltech	Russian Federation

Pfohl	Moritz	Karlsruher Institut für Nanotechnologie	Germany
Piao	Yanmei	National Institute of Standards and Technology	USA
Podila	Ramakrishna	Clemson University	USA
Popov	Andrey	Institute for Spectroscopy Russian Academy of Science	Russian Federation
Pötschke	Petra	Leibniz-Institut für Polymerforschung Dresden e.V.	Germany
Predtechenskiy	Mikhail	OCSIAI Group	Russian Federation
Pyatkov	Felix	Karlsruhe Institute for Technology (KIT)	Germany
Reguero	Victor	IMDEA Materials	Spain
Reinoso	Carlos	Elektronische Materialeigenschaften	Austria
Rennhofer	Harald	Institute of Physics and Materials Science, BOKU Vienna	Austria
Rohringer	Philip	Elektronische Materialeigenschaften	Austria
Rother	Marcel	Institute for Physical Chemistry, Universität Heidelberg	Germany
Sadeghpour	Hossein	ITAMP, Harvard Univ.	USA
Saito	Riichiro	Tohoku University	Japan
Saito	Susumu	Department of Physics, Tokyo of Technology	Japan
Saito	Yahachi	Dept. of Quantum Eng., Nagoya University	Japan
Sakurai	Masahiro	The University of Texas at Austin	USA
Salazar Rios	Jorge Mario	University of Groningen	Netherlands
Sandström	Robin	Umeå University - Department of Physics	Sweden
Sasaki	Fusako	TASC	Japan
Scalia	Giusy	University of Luxembourg	Luxemburg
Schießl	Stefan Patrick	Institute for Physical Chemistry, Universität Heidelberg	Germany
Schöppler	Friedrich	Julius-Maximilian University Würzburg, Institute of Physical and Theoretical Chemistry	Germany
Schuler	Simone	Technische Universität Wien	Austria
Searles	Thomas A	Howard University	USA
Sekiguchi	Atsuko	Technology Research Association for Single wall carbon nanotubes (TASC)	Japan
Shaffer	Milo	Imperial College	United Kingdom
Sharma	Renu	National Institute of Standards and Technology	USA
Shawky Ghareeb	Ahmed	Central Metallurgical R & D Institute	Egypt
Shearer	Cameron	Flinders University	Australia
SHI	Lei	University of Vienna	Austria
Shibuta	Yasushi	The University of Tokyo	Japan
Shinohara	Hisanori	Nagoya University	Japan
Shiozawa	Hidetsugu	Elektronische Materialeigenschaften	Austria
Shiraki	Tomohiro	Graduate school of Engineering, Kyushu University	Japan
Shlafman	Michael	Technion - Israel Institute of Technology	Israel
Simon	Ferenc	Budapest University of Technology and Economics	Hungary
Singer	Gerald	University of Natural Resources and Life Sciences Vienna	Austria
Sun	Dongming	Institute of Metal Research, Chinese Academy of Sciences	China
Sun	Haibin	Xinyang Normal University	China
Sundaram	Rajyashree	Technology Research Association for SWCNTs	Japan
Susi	Toma	Physik Nanostrukturierter Materialien	Austria
Suzuki	Daichi	Tokyo Institute of Technology	Japan
Suzuki	Hal	Osaka University	Japan
Suzuki	Hiroo	Department of Electronic Engineering, Tohoku University	Japan
Suzuki	Satoru	NTT Basic Research Labs.	Japan
Svensson	Krister	Karlstad University	Sweden
Syari'ati	Ali	University of Groningen	Netherlands
Tabachnik	Tal	Technion - Israel Institute of Technology	Israel
Tabata	Hiroshi	Osaka University	Japan
Takaki	Hiroshi	Keio University	Japan
Takano	Yuta	iCeMS, Kyoto University	Japan
Takenobu	Taishi	Nagoya University	Japan

Tanaka	Fumiaki	Technology Research Association for Single Wall Carbon Nanotubes	Japan
Taubert	Stefan	University of Helsinki	Finland
Tavakkoli	Mohammad	Department of Chemistry, School of Chemical Technology, Aalto University	Finland
Teichert	Fabian	Dresden Center for Computational Materials Science (DCMS)	Germany
Tejima	Syogo	Research Organization for Information Science & Technology	Japan
Tomanek	David	Michigan State University	USA
Tomanek	David	Michigan State University	USA
Tomori	Hikari	University of Tsukuba	Japan
Toshimitsu	Fumiyuki	Kyushu University	Japan
Tripathi	Mukesh Kumar	Physik Nanostrukturierter Materialien	Austria
Tsuji	Takashi	Technology Research Association for Single Wall Carbon Nanotubes (TASC)	Japan
Tune	Daniel	Karlsruhe Institute of Technology	Germany
Uesugi	Kenji	Furukawa Research Inc.	Japan
Ukhtary	Muhammad S	Tohoku University	Japan
Ushiyama	Takuya	Graduate School of Engineering, Nagoya University	Japan
Van Bezouw	Stein	University of Antwerp	Belgium
Varlamov	Yuriy	ISCTE LLC	Russian Federation
Verbitskiy	Nikolay	Elektronische Materialeigenschaften	Austria
Vets	Charlotte	University of Antwerp, Department of Chemistry, Research group Plasmat	Belgium
Vijayaraghavan	Aravind	University of Manchester	United Kingdom
von dem Bussche	Annette	Brown University	USA
Wagberg	Thomas	Umea University, Department of Physics	Sweden
Wagner	Christian	Technische Universität Chemnitz	Germany
Wang	Eunice	FUJIFILM Dimatix, Inc.	USA
Wang	Jiangtao	Tsinghua University	China
Wang	Xinhe	Tsinghua-Foxconn Nanotechnology Research Center	China
Wanko	Marius	University of the Basque Country	Spain
Wei	Fei	Tsinghua University	China
Wei	Haoming	Tsinghua University	China
WEI	LILI	Beijing Heli Chengda Machinery Equipment Co.,Ltd	China
Wei	Xiaojun	National Institute of Advanced Industrial Science and Technology (AIST)	Japan
Wei	Yang	Tsinghua University	China
Wenseleers	Wim	University of Antwerp	Belgium
Wenyun	Wu	Tsinghua University	China
Wick	Peter	Empa, Swiss Federal Laboratories for Materials Science and Technology	Switzerland
Wild	Stefan	Universität Erlangen-Nürnberg	Germany
Wirtz	Ludger	University of Luxembourg	Luxemburg
Wolski	Pawel	Jerzy Haber Institute of Catalysis and Surface Chemistry Polish Academy of Sciences	Poland
Xiang	Rong	The University of Tokyo	Japan
Xiao	Xiaoyang	Tsinghua University	China
Xie	Huanhuan	Tsinghua University	China
Xie	Sishen	INSTITUTE OF PHYSICS, THE CHINESE ACADEMY OF SCIENCES	China
Xu	Bin	Department of engineering, Tohoku University	Japan
Xu	Yan	Huawei Technologies Co.ltd	China
Yaish	Yuval	Andrew and Erna Viterbi Faculty of Electrical Engineering	Israel
Yamada	Kentaro	NIKON CORPORATION	Japan
Yamanaka	Ayaka	University of Tsukuba	Japan
Yamashita	Satoshi	FURUKAWA ELECTRIC CO., LTD.	Japan
Yan	Lingjia	Tsinghua University	China
Yanagi	Kazuhiro	Tokyo Metropolitan University	Japan

Yang	Feng	Peking University	China
Yang	Juan	Peking University	China
Yang	Kiwook	Keimyung university school of medicine	South Korea
Yang	Yingjun	Key Laboratory for the Physics and Chemistry of Nanodevices and Department of Electronics, Peking University, Beijing	China
Yasunishi	Tomohiro	Nagoya University	Japan
Yoshikawa	Ryo	The University of Tokyo	Japan
Yoshino	Kazuki	Tokyo University of Science	Japan
YUMURA	Motoo	AIST	Japan
Zakharko	Yuriy	University of Heidelberg	Germany
Zaumseil	Jana	UNIVERSITÄT HEIDELBERG	Germany
Zeevi	Gilad	Molecular electronics Lab - Technion	Israel
Zhang	Daqi	College of Chemistry and Molecular Engineering, Peking University	China
Zhang	Jin	Peking University	China
Zhang	Jin	Tsinghua University	China
Zhang	Ling	Tsinghua-Foxconn Nanotechnology Research Center, Tsinghua University	China
Zhang	Luman	Department of Materials Engineering, KU Leuven	Belgium
Zhang	Panpan	Peking University	China
Zhang	Shuchen	Peking University	China
Zhao	Qiuchen	Peking University	China
Zhao	Wei	Tsinghua University	China
Zhao	Yudan	Tsinghua University	China
Zheng	Ming	NIST	USA
Zheng	Ruiting	Beijing Normal University	China
Zhu	Zhenxing	Tsinghua University	China